RENESAS

HA17431VPJ/PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA

Shunt Regulator

REJ03D0892-0100 Rev.1.00 Apr 03, 2007

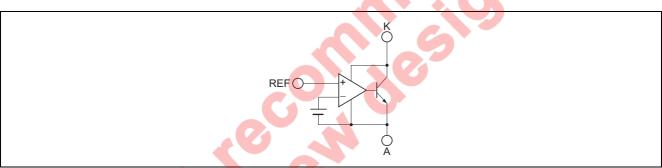
Description

The HA17431 series is temperature-compensated variable shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The on-chip high-precision reference voltage source can provide $\pm 1\%$ accuracy in the V versions, which have a V_{KA} max of 16 volts.

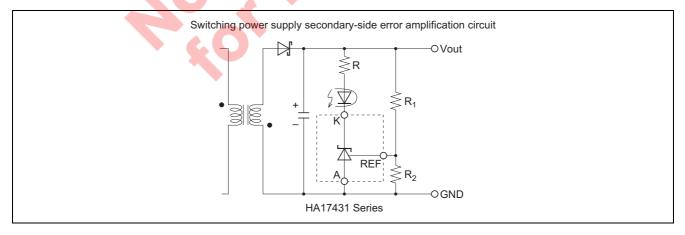
Features

- The V versions provide 2.500 V $\pm 1\%$ at Ta = 25°C
- The reference voltage has a low temperature coefficient
- The UPAKV miniature packages are optimal for use on high mounting density circuit boards

Block Diagram



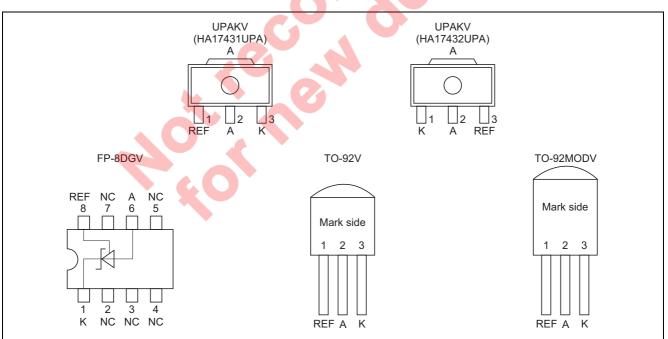
Application Circuit Example



Ordering Information

| | | Refere | nce voltage (at 2 | 25°C) | | |
|------------|-------------|---|--|--|--------------------------------|-----------------------------------|
| | Item | Normal Version ±4% 2.395V to 2.495V to 2.595V | A Version ±2.2% 2.440V to 2.495V to 2.550V | V Version ±1% 2.475V to 2.500V to 2.525V | Package Code (Package Name) | Operating Temperature Range |
| | HA17431FPAJ | | 0 | | PRSP0008DE-B (FP-8DGV) | |
| | HA17431FPJ | 0 | | | PRSP0008DE-B (FP-8DGV) | |
| Car use | HA17431PAJ | | 0 | | PRSS0003DC-A (TO-92MODV) | –40 to +85°C |
| Caluse | HA17431PJ | 0 | | | PRSS0003DC-A (TO-92MODV) | -40 to +85 C |
| | HA17431PNAJ | | 0 | | PRSS0003DA-A (TO-92V) | |
| | HA17431VPJ | | | 0 | PRSS0003DA-A (TO-92V) | |
| Industrial | HA17431UPA | | 0 | 0 | PLZZ0004CA-A (UPAKV) | –20 to +85°C |
| use | HA17432UPA | | 0 | | PLZZ0004CA-A (UPAKV) | -20 10 +05 C |

Pin Arrangement



Absolute Maximum Ratings

| () | (Ta | = | 25° | C) |
|----|-----|---|-----|----|
|----|-----|---|-----|----|

| Item | Symbol | HA17431VPJ | HA17431UPA | HA17432UPA | Unit | Notes |
|-----------------------------|-----------------|--------------------|--------------------|--------------------|------|-------|
| Cathode voltage | V _{KA} | 16 | 40 | 40 | V | 1 |
| Continuous cathode current | Ι _K | –50 to +50 | –100 to +150 | -100 to +150 | mA | |
| Reference input current | Iref | –0.05 to +10 | -0.05 to +10 | –0.05 to +10 | mA | |
| Power dissipation | Pτ | 500 * ² | 800 * ⁵ | 800 * ⁵ | mW | 2, 5 |
| Operating temperature range | Topr | -40 to +85 | -20 to +85 | -20 to +85 | °C | |
| Storage temperature | Tstg | –55 to +150 | -55 to +150 | –55 to +150 | °C | |

| Item | Symbol | HA17431PNAJ | HA17431PJ/PAJ | HA17431FPJ/FPAJ | Unit | Notes |
|-----------------------------|-----------------|--------------------|--------------------|--------------------|------|---------|
| Cathode voltage | V _{KA} | 40 | 40 | 40 | V | 1 |
| Continuous cathode current | Ι _κ | -100 to +150 | -100 to +150 | -100 to +150 | mA | |
| Reference input current | Iref | -0.05 to +10 | -0.05 to +10 | -0.05 to +10 | mA | |
| Power dissipation | P _T | 500 * ² | 800 * ³ | 500 * ⁴ | mW | 2, 3, 4 |
| Operating temperature range | Topr | -40 to +85 | -40 to +85 | -40 to +85 | °C | |
| Storage temperature | Tstg | -55 to +150 | -55 to +150 | -55 to +125 | °C | |

Notes: 1. Voltages are referenced to anode.

- 2. Ta \leq 25°C. If Ta > 25°C, derate by 4.0 mW/°C.
- 3. Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

No.

- 50 mm × 50 mm × 1.5mmt glass epoxy board (5% wiring density), Ta ≤ 25°C. If Ta > 25°C, derate by 5 mW/°C.
- 5. 15 mm × 25 mm × 0.7mmt alumina ceramic board, Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

Electrical Characteristics

HA17431VPJ

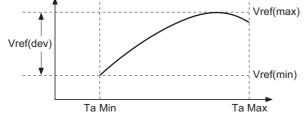
 $(Ta = 25^{\circ}C, I_{K} = 10 \text{ mA})$

| ltem | Symbol | Min | Тур | Max | Unit | Test Conditions | Notes |
|---|--------------------------------|-------|-------|-------|--------|--|-------|
| Reference voltage | Vref | 2.475 | 2.500 | 2.525 | V | V _{KA} = Vref | |
| Reference voltage temperature deviation | Vref(dev) | — | 10 | — | mV | V_{KA} = Vref, Ta = -20°C to +85°C | 1 |
| Reference voltage temperature coefficient | ∆Vref/∆Ta | — | ±30 | — | ppm/°C | V _{KA} = Vref, 0°C to 50°C gradient | |
| Reference voltage regulation | $\Delta V ref / \Delta V_{KA}$ | _ | 2.0 | 3.7 | mV/V | V _{KA} = Vref to 16 V | |
| Reference input current | Iref | _ | 2 | 6 | μA | R_1 = 10 k Ω , R_2 = ∞ | |
| Reference current temperature deviation | Iref(dev) | _ | 0.5 | _ | μA | R ₁ = 10 kΩ, R ₂ = ∞, Ta = –20°C to +85°C | |
| Minimum cathode current | Imin | | 0.4 | 1.0 | mA | V _{KA} = Vref | 2 |
| Off state cathode current | loff | | 0.001 | 1.0 | μA | V _{KA} = 16 V, Vref = 0 V | |
| Dynamic impedance | Zka | — | 0.2 | 0.5 | Ω | V_{KA} = Vref, I_{K} = 1 mA to 50 mA | |

HA17431PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA

| | | | | | | | $(Ta = 25^{\circ}C, I_K)$ | = 10 mA) |
|---------------------------|-----------------------------|-------|-------|-------|------|------------------------------------|---------------------------|-----------|
| Item | Symbol | Min | Тур | Max | Unit | Tes | t Conditions | Notes |
| Reference voltage | Vref | 2.440 | 2.495 | 2.550 | V | V _{KA} = Vref | | А |
| | | 2.395 | 2.495 | 2.595 | | | | Normal |
| Reference voltage | Vref(dev) | | 11 | (30) | mV | V _{KA} = Vref | Ta = | 1, 3, 4 |
| temperature deviation | | | | | | | –20°C to +85°C | |
| | | | 5 | (17) | | | Ta = 0°C to +70°C | 1, 3, 5 |
| Reference voltage | $\Delta Vref/\Delta V_{KA}$ | Ι | 1.4 | 3.7 | mV/V | V _{KA} = Vref to 10 V | | |
| regulation | | _ | 1 | 2.2 | | V _{KA} = 10 V | to 40 V | |
| Reference input current | Iref | - | 3.8 | 6 | μA | R ₁ = 10 kΩ | , R₂ = ∞ | |
| Reference current | Iref(dev) | _ | 0.5 | (2.5) | μA | R ₁ = 10 kΩ | , R₂ = ∞, | 3 |
| temperature deviation | | | | | | Ta = 0°C to +70°C | | |
| Minimum cathode current | Imin | | 0.4 | 1.0 | mA | V _{KA} = Vref | | 2 |
| Off state cathode current | loff | — | 0.001 | 1.0 | μA | V _{KA} = 40 V, Vref = 0 V | | |
| Dynamic impedance | ZKA | | 0.2 | 0.5 | Ω | V _{KA} = Vref, | | |
| | | | | | | $I_{K} = 1 \text{ mA to}$ | o 100 mA | |

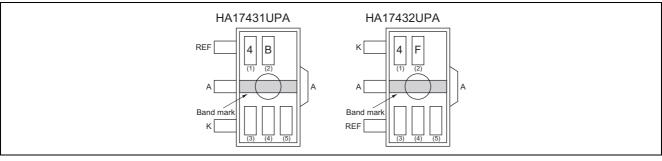
Notes: 1. Vref(dev) = Vref(max) – Vref(min)



- 2. Imin is given by the cathode current at Vref = $Vref_{(IK=10mA)} 15 \text{ mV}$.
- 3. The maximum value is a design value (not measured).
- 4. HA17431PJ/PAJ/FPJ/FPAJ/PNAJ
- 5. HA17431UPA, HA17432UPA

UPAKV Marking Patterns

The marking patterns shown below are used on UPAKV products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

| Product | (1) | (2) |
|------------|-----|-----|
| HA17431UPA | 4 | В |
| HA17432UPA | 4 | F |

Dec. Μ

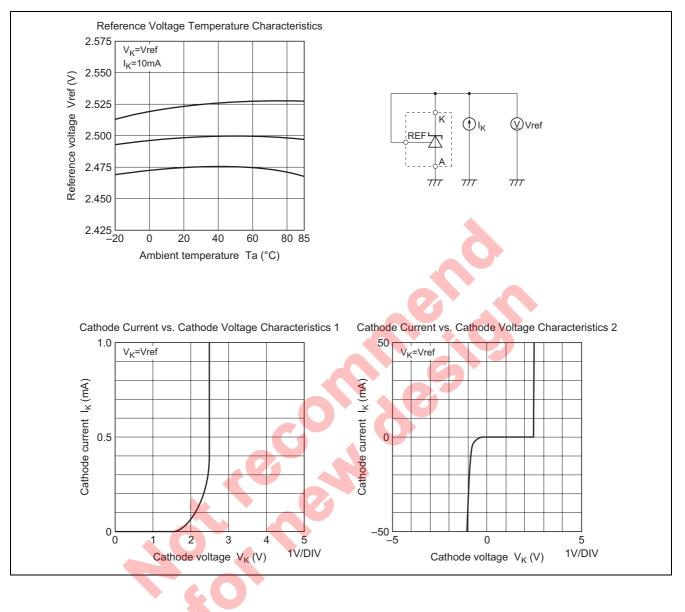
3. The letter (3) shows the production year code (the last digit of the year).

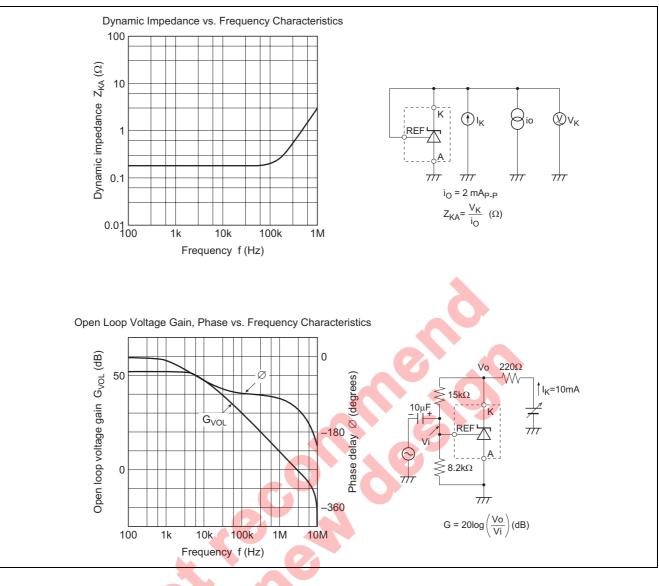
| 4. | . The letter (4) shows the production month code (see table below). | | | | | | | | | | | |
|----|---|------|------|------|------|------|------|------|------|------|------|------|
| | Production month | Jan. | Feb. | Mar. | Apr. | May. | Jun. | Jul. | Aug. | Sep. | Oct. | Nov. |
| | Marked code | А | В | С | D | E | F | G | H | J | К | L |

5. The letter (5) shows manufacturing code.

Characteristics Curves

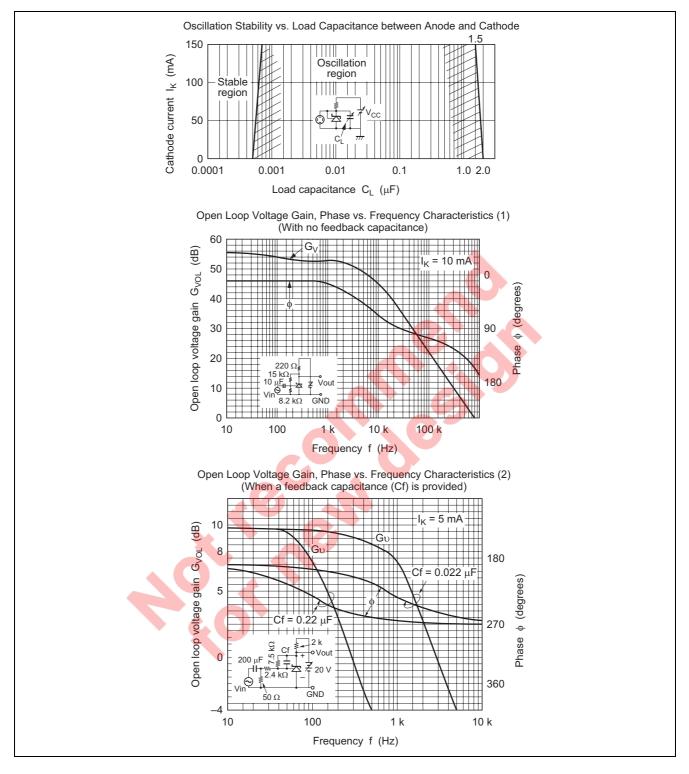
HA17431VPJ

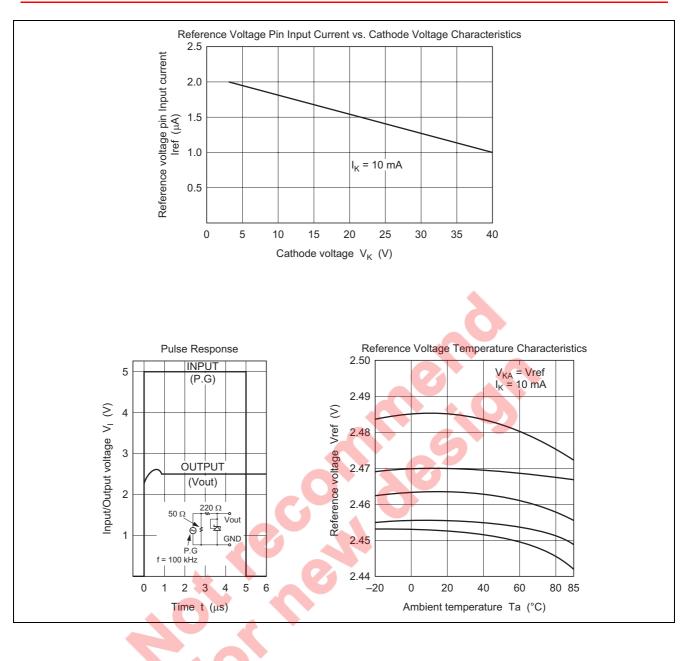


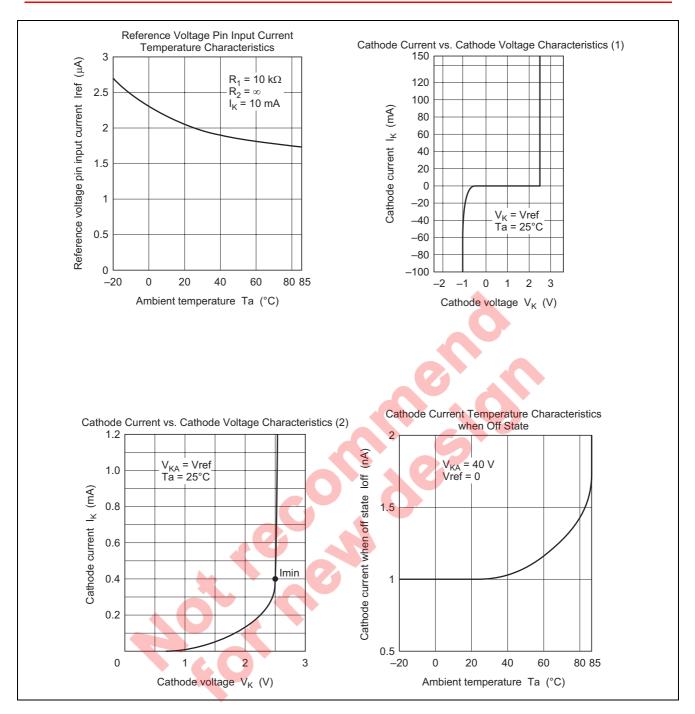




HA17431PJ/PAJ/FPAJ/PNAJ/UPA, HA17432UPA







Application Examples

As shown in the figure on the right, this IC operates as an inverting amplifier, with the REF pin as input pin. The openloop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 3.8 μ A Typ (V version: Iref = 2 μ A Typ). The output impedance of the output pin K (cathode) is defined as dynamic impedance Z_{KA}, and Z_{KA} is low (0.2 Ω) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.

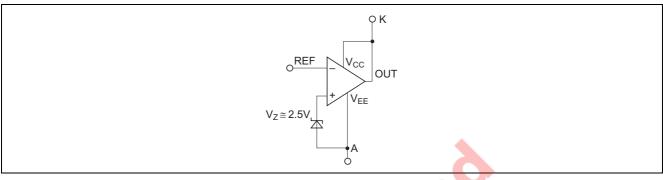


Figure 1 Operation Diagram

Application Hints

| - | | |
|-----|--|--|
| No. | Application Example | Description |
| 1 | Reference voltage generation circuit Vin $\bigcirc - \checkmark \lor \bigcirc \lor \bigcirc \lor \lor \circ \lor$ | This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_K \ge 1$ mA. Output is fixed at Vout $\cong 2.5$ V. The external capacitor C_L ($C_L \ge 3.3 \ \mu$ F) is used to prevent oscillation in normal applications. |
| 2 | Variable output shunt regulator circuit Vin O - VV - OVout $R_1 = Iref K - CL$ $R_2 = OGND$ | This is circuit 1 above with variable output provided. Here, Vout $\cong 2.5 \text{ V} \times \frac{(R_1 + R_2)}{R_2}$ Since the reference input current Iref = 3.8 µA Typ (V version: Iref = 2 µA Typ) flows through R ₁ , resistance values are chosen to allow the resultant voltage drop to be ignored. |

Application Hints (cont.)

| No. | Application Example | Description |
|-----|---|---|
| 3 | Single power supply inverting comparator circuit | $\begin{array}{c c} \mbox{This is an inverting type comparator with an input threshold voltage} \\ \mbox{of approximately 2.5 V. Rin is the REF pin protection resistance,} \\ \mbox{with a value of several } k\Omega \mbox{ to several tens of } k\Omega. \\ \mbox{R}_L \mbox{ is the load resistance, selected so that the cathode current } I_K \geq 1 \\ \mbox{mA when Vout is low.} \\ \hline \mbox{Condition Vin Vout IC} \\ \hline \mbox{C1 Less then } 2.5 \ V \ V_{CC} \ (V_{OH}) \ OFF \\ \hline \mbox{C2 } 2.5 \ V \ or more Approx. 2 \ V \ (V_{OL}) \ ON \end{array}$ |
| 4 | GNDO AC amplifier circuit | This is an AC amplifier with voltage gain G = $-R_1 / (R_2 / / R_3)$. The |
| | $Cin R_{3}$ R_{2} | input is cut by capacitance Cin, so that the REF pin is driven by the AC input signal, centered on 2.5 V_{DC} . R ₂ also functions as a resistance that determines the DC cathode potential when there is no input, but if the input level is low and there is no risk of Vout clipping to V _{CC} , this can be omitted. To change the frequency characteristic, Cf should be connected as indicated by the dotted line. |
| 5 | Switching power supply error amplification circuit | This circuit performs control on the secondary side of a transformer, and is often used with a switching power supply that employs a photocoupler for offlining. The output voltage (between V+ and V–) is given by the following formula: Vout $\cong 2.5 \text{ V} \times \frac{(\text{R}_1 + \text{R}_2)}{\text{R}_2}$ In this circuit, the gain with respect to the Vout error is as follows: $G = \frac{\text{R}_2}{(\text{R}_1 + \text{R}_2)} \times \begin{bmatrix} \text{HA17431 open} \\ \text{loop gain} \end{bmatrix} \times \begin{bmatrix} \text{photocoupler} \\ \text{total gain} \end{bmatrix}$ As stated earlier, the HA17431 open-loop gain is 50 to 60 dB. |

Application Hints (cont.)

| No. | Application Example | Description |
|-----|--|---|
| 6 | Constant voltage regulator circuit $V_{CC} \circ R_1 \rightarrow Q$ $R_1 \rightarrow Q$ $R_2 \rightarrow V_{OUT}$ $GND \circ Cf \rightarrow R_3$ $GND \circ FT$ | This is a 3-pin regulator with a discrete configuration, in which the output voltage Vout = $2.5 \text{ V} \times \frac{(\text{R}_2 + \text{R}_3)}{\text{R}_3}$ R ₁ is a bias resistance for supplying the HA17431 cathode current and the output transistor Q base current. |
| 7 | Discharge type constant current circuit | This circuit supplies a constant current of $I_L \cong \frac{2.5 \text{ V}}{\text{R}_S}$ [A] into the load. Caution is required since the HA17431 cathode current is also superimposed on I_L . The requirement in this circuit is that the cathode current must be greater than Imin = 1 mA. The I_L setting therefore must be on the order of several mA or more. |
| 8 | Induction type constant current circuit | In this circuit, the load is connected on the collector side of transistor Q in circuit 7 above. In this case, the load floats from GND, but the HA17431 cathode current is not superimposed on I _L , so that I _L can be kept small (1 mA or less is possible). The constant current value is the same as for circuit 7 above: $I_L \cong \frac{2.5 V}{R_S}$ [A] |

Design Guide for AC-DC SMPS (Switching Mode Power Supply)

Use of Shunt Regulator in Transformer Secondary Side Control
This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the
secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.

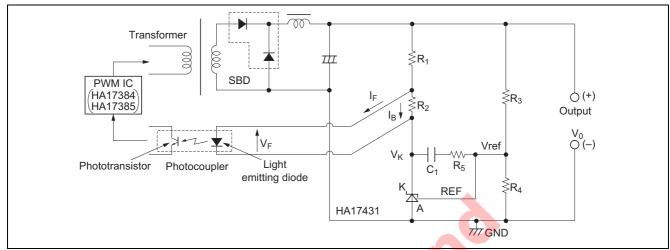


Figure 2 Typical Shunt Regulator/Error Amplifier

- 2. Determination of External Constants for the Shunt Regulator
 - A. DC characteristic determination

In figure 2, R_1 and R_2 are protection resistor for the light emitting diode in the photocoupler, and R_2 is a bypass resistor to feed I_K minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$\mathsf{R}_1 = \frac{\mathsf{V}_0 - \mathsf{V}_\mathsf{F} - \mathsf{V}_\mathsf{K}}{\mathsf{I}_\mathsf{F} + \mathsf{I}_\mathsf{B}} \ , \ \mathsf{R}_2 = \frac{\mathsf{V}_\mathsf{F}}{\mathsf{I}_\mathsf{B}}$$

 V_K is the HA17431 operating voltage, and is set at around 3 V, taking into account a margin for fluctuation. R_2 is the current shunt resistance for the light emitting diode, in which a bias current I_B of around 1/5 I_F flows. Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times \text{Vref, Vref} = 2.5 \text{ V Typ}$$

The absolute values of R_3 and R_4 are determined by the HA17431 reference input current Iref and the AC characteristics described in the next section. The Iref value is around 3.8 μ A Typ. (V version: 2 μ A Typ)

B. AC characteristic determination

This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.

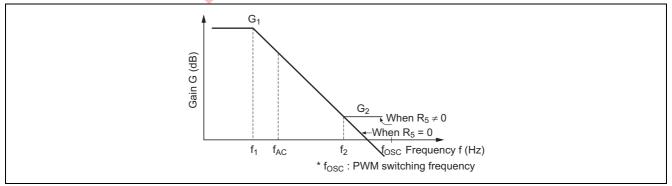


Figure 3 HA17431 Error Amplification Characteristic

In Figure 3, the following formulas are obtained: Gain

 $G_1 = G_0 \approx 50 \text{ dB to } 60 \text{ dB}$ (determined by shunt regulator)

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies

 $f_1 = 1/(2\pi C_1 G_0 R_3)$

 $f_2 = 1/(2\pi C_1 R_5)$

 G_0 is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation $\Delta V ref / \Delta V_{KA}$, and is approximately 50 dB.

3. Practical Example

Consider the example of a photocoupler, with an internal light emitting diode $V_F = 1.05$ V and $I_F = 2.5$ mA, power supply output voltage $V_2 = 5$ V, and bias resistance R_2 current of approximately 1/5 I_F at 0.5 mA. If the shunt regulator $V_K = 3$ V, the following values are found.

$$R_{1} = \frac{5V - 1.05V - 3V}{2.5mA + 0.5mA} = 316(\Omega) (330\Omega \text{ from E24 series})$$

$$R_{2} = \frac{1.05V}{0.5mA} = 2.1(k\Omega) (2.2k\Omega \text{ from E24 series})$$

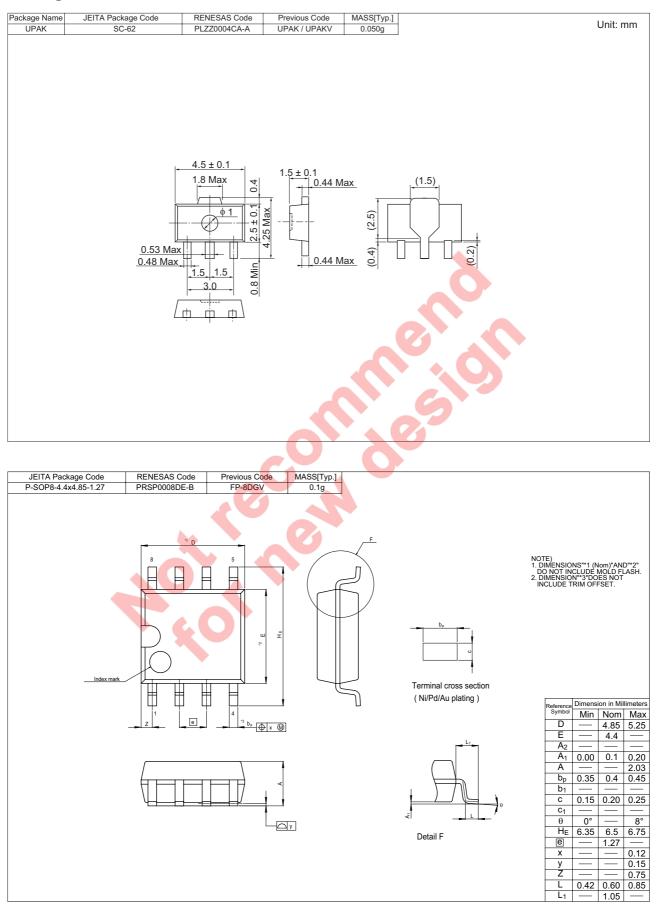
Next, assume that $R_3 = R_4 = 10 \text{ k}\Omega$. This gives a 5 V output. If $R_5 = 3.3 \text{ k}\Omega$ and $C_1 = 0.022 \mu\text{F}$, the following values are found.

 $G_2 = 3.3 \text{ k}\Omega / 10 \text{ k}\Omega = 0.33 \text{ times} (-10 \text{ dB})$

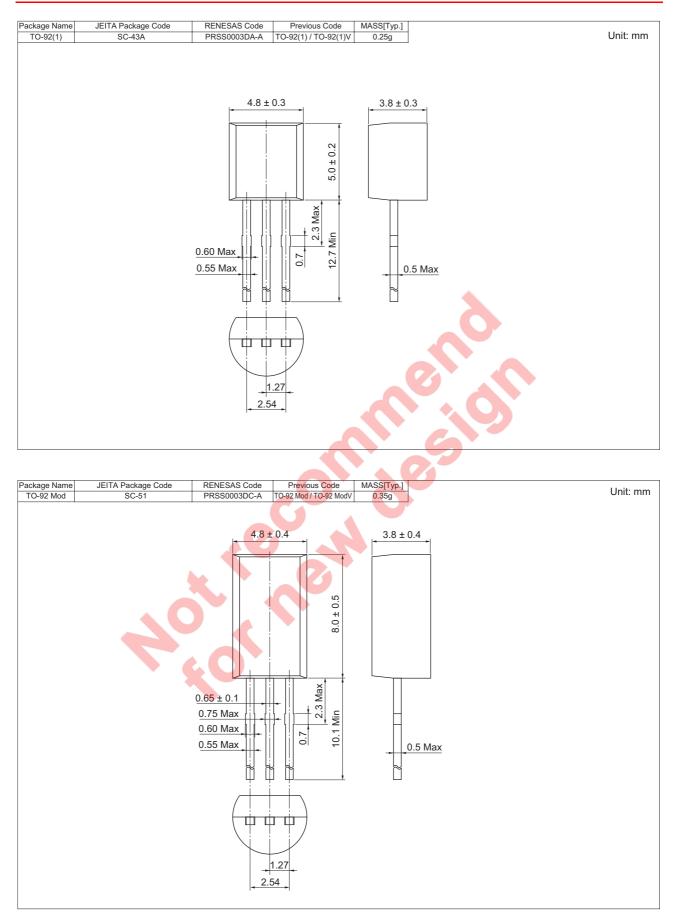
 $f_1 = 1 / (2 \times \pi \times 0.022 \ \mu F \times 316 \times 10 \ k\Omega) = 2.3$ (Hz)

 $f_2 = 1 / (2 \times \pi \times 0.022 \ \mu F \times 3.3 \ k\Omega) = 2.2 \ (kHz)$

Package Dimensions



HA17431VPJ/PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA



RenesasTechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- PencessPectrophysecore, Sales Strategic Planning Di. Ngop Bidg., 2-6-2, Otte-mechl, Chiyode-Au, Tokyo 100-0004, Japat Distribution of the sevent s



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Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.

Unit 204, 205, AZIACenter, No. 1233 Lujiazul Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510